26.8% Improved Triple Junction (ITJ) Solar Cells

Features

- High efficiency n/p design (28°C, AM0)
 - -BOL: 26.8% min. average efficiency @ maximum power (26.5% @ load voltage)
 - -EOL: 22.5% min. average efficiency @ maximum power (22.3% @ load voltage), 1 MeV 1E15 e/cm²
- Integral bypass diode protection
- Transparent insertion into existing systems



Product Description			
Substrate	Germanium		
Solar Cell Structure	GalnP ₂ /GaAs/Ge		
Method of GaAs Growth	Metal Organic Vapor Phase Epitaxy		
Device Design	Monolithic, two terminal triple junction. n/p GalnP ₂ , GaAs, and Ge solar cells interconnected with two tunnel junctions		
Sizes	Up To 31 cm ²		
Assembly Method	Multiple techniques including soldering, welding, thermocompression, or ultrasonic wire bonding		
Integral Diode	Si diode integrated into recess on back side		
Note: Other Variations Are Available Upon Request			

Heritage

- More than 2000 kW of multi-junction cells delivered
- More than 675 kW of multi-junction arrays on orbit
- 1 MW annual capacity cells, panels & arrays
- On orbit performance for multi-junction solar cells validated to ± 1.5% of ground test results

Intellectual Property

This product is protected by the following patents:

- 6,380,601
- 6,150,603
- 6,255,580

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Photovoltaic Products www.spectrolab.com

Typical Electrical Parameters

(AM0 (135.3 mW/cm²) 28 ℃, Bare Cell)

$$\begin{split} J_{sc} &= 16.90 \text{ mA/cm}^2 \\ J_{mp} &= 16.00 \text{ mA/cm}^2 \\ J_{load \, min \, avg} &= 16.10 \text{ mA/cm}^2 \\ V_{oc} &= 2.565 \text{ V} \\ V_{mp} &= 2.270 \text{ V} \\ V_{load} &= 2.230 \text{ V} \\ Cff &= 0.84 \\ Eff_{load} &= 26.5\% \end{split}$$

Radiation Degradation

(Fluence 1MeV Electrons/cm²)

Parameters	1x10 ¹⁴	5x10 ¹⁴	1x10 ¹⁵
Imp/Imp ₀	1.00	0.98	0.96
Vmp/Vmp ₀	0.94	0.90	0.88
Pmp/Pmp ₀	0.94	0.88	0.84

Thermal Properties

Solar Absorptance= 0.92 (Ceria Doped Microsheet)

Emittance (Normal) = 0.85 (Ceria Doped Microsheet)

Weight

Eff_{mp}= 26.8%

84 mg/ cm² (Bare) @ 140 µm (5.5 mil) Thickness

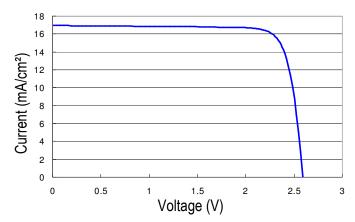
Thickness of 175 μm typical with weight equivalence of a 140 μm thick cell.

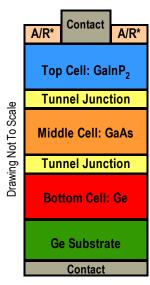
Temperature Coefficients (10 ℃ - 80 ℃)

Parameters	BOL	1x10 ¹⁵ (1 MeV e/cm²)
Jmp (µA/cm²/°C)	7.3	9.5
Jsc (µA/cm²/°C)	11.5	12.4
Vmp (mV/°C)	-6.2	-6.6
Voc (mV/°C)	-5.9	-6.5

Typical IV Characteristic

AM0 (135.3 mW/cm2) 28°C, Bare Cell





*A/R: Anti-Reflective Coating

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